NSN 5961-01-111-4724

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View Online at https://aerobasegroup.com/nsn/5961-01-111-4724 **Inclosure Material:** Metal **Overall Length:** 1.572 inches **Overall Height:** Between 0.250 inches and 0.450 inches Overall Width: 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 collector to base voltage, dc and 300.0 collector to emitter voltage, dc and 5.0 emitter to base voltage, dc **Current Rating Per Characteristic:** Between 10.00 amperes source cutoff current and 40.00 amperes source cutoff current **Power Rating Per Characteristic:** 200.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 81755-c8646 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: